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# FDS8840NZ

## N-Channel PowerTrench® MOSFET

40 V, 18.6 A, 4.5 mΩ

### Features

- Max  $r_{DS(on)}$  = 4.5 mΩ at  $V_{GS} = 10\text{ V}$ ,  $I_D = 18.6\text{ A}$
- Max  $r_{DS(on)}$  = 6.0 mΩ at  $V_{GS} = 4.5\text{ V}$ ,  $I_D = 14.9\text{ A}$
- HBM ESD protection level of 6 kV typical(note 3)
- High performance trench technology for extremely low  $r_{DS(on)}$  and fast switching
- High power and current handling capability
- Termination is Lead-free and RoHS Compliant

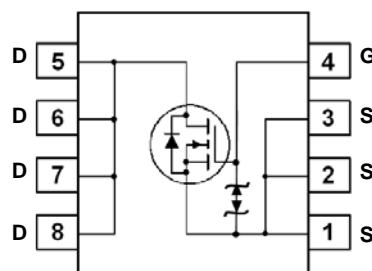
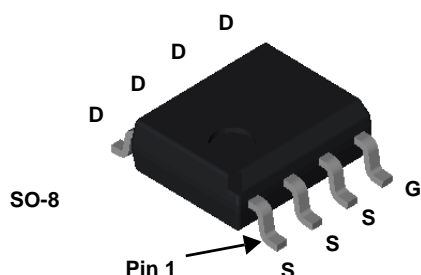


### General Description

The FDS8840NZ has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest  $r_{DS(on)}$  while maintaining excellent switching performance.

### Applications

- Synchronous Buck for Vcore and Server
- Notebook Battery Pack
- Load Switch



### MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DS}$	Drain to Source Voltage	40	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current -Continuous	18.6	A
	-Pulsed	63	
$E_{AS}$	Single Pulse Avalanche Energy (Note 4)	600	mJ
$P_D$	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1a)	2.5	W
	Power Dissipation $T_A = 25^\circ\text{C}$ (Note 1b)	1.0	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case (Note 1)	25	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDS8840NZ	FDS8840NZ	SO8	13 "	12 mm	2500 units

**Electrical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off Characteristics**

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250\ \mu\text{A}$ , $V_{GS} = 0\ \text{V}$	40			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25^\circ\text{C}$		31		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 32\ \text{V}$ , $V_{GS} = 0\ \text{V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\ \text{V}$ , $V_{DS} = 0\ \text{V}$			$\pm 10$	$\mu\text{A}$

**On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\ \mu\text{A}$	1.0	1.8	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25^\circ\text{C}$		-6		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\ \text{V}$ , $I_D = 18.6\ \text{A}$		3.9	4.5	m $\Omega$
		$V_{GS} = 4.5\ \text{V}$ , $I_D = 14.9\ \text{A}$		4.6	6.0	
		$V_{GS} = 10\ \text{V}$ , $I_D = 18.6\ \text{A}$ , $T_J = 125^\circ\text{C}$		5.9	7.0	
$g_{FS}$	Forward Transconductance	$V_{DS} = 5\ \text{V}$ , $I_D = 18.6\ \text{A}$		83		S

**Dynamic Characteristics**

$C_{iss}$	Input Capacitance	$V_{DS} = 20\ \text{V}$ , $V_{GS} = 0\ \text{V}$ , $f = 1\ \text{MHz}$		5665	7535	pF
$C_{oss}$	Output Capacitance			650	865	pF
$C_{rss}$	Reverse Transfer Capacitance			445	670	pF
$R_g$	Gate Resistance			1.2		$\Omega$

**Switching Characteristics**

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 20\ \text{V}$ , $I_D = 18.6\ \text{A}$ , $V_{GS} = 10\ \text{V}$ , $R_{GEN} = 6\ \Omega$		18	32	ns
$t_r$	Rise Time			13	23	ns
$t_{d(off)}$	Turn-Off Delay Time			57	103	ns
$t_f$	Fall Time			11	20	ns
$Q_g$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $10\ \text{V}$	$V_{DD} = 20\ \text{V}$ , $I_D = 18.6\ \text{A}$	103	144	nC
$Q_g$	Total Gate Charge	$V_{GS} = 0\ \text{V}$ to $5\ \text{V}$		54	76	nC
$Q_{gs}$	Gate to Source Charge			16		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			19		nC

**Drain-Source Diode Characteristics**

$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\ \text{V}$ , $I_S = 18.6\ \text{A}$		0.8	1.2	V
		$V_{GS} = 0\ \text{V}$ , $I_S = 2.1\ \text{A}$		0.7	1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = 18.6\ \text{A}$ , $di/dt = 100\ \text{A}/\mu\text{s}$		33	53	ns
$Q_{rr}$	Reverse Recovery Charge			21	34	nC

**NOTES:**

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a)  $50^\circ\text{C}/\text{W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b)  $125^\circ\text{C}/\text{W}$  when mounted on a minimum pad.

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0%.

3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

4. Starting  $T_J = 25^\circ\text{C}$ ,  $L = 3\ \text{mH}$ ,  $I_{AS} = 20\ \text{A}$ ,  $V_{DD} = 40\ \text{V}$ ,  $V_{GS} = 10\ \text{V}$ .

## Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

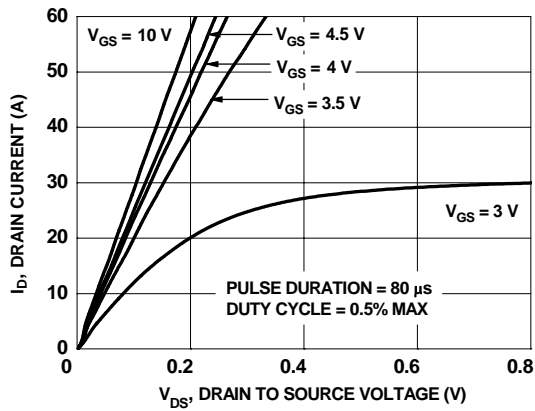


Figure 1. On-Region Characteristics

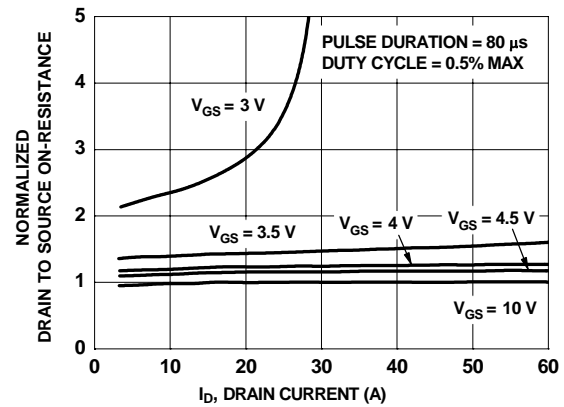


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

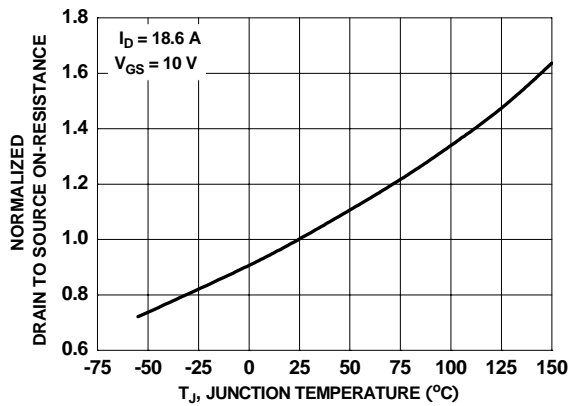


Figure 3. Normalized On-Resistance vs Junction Temperature

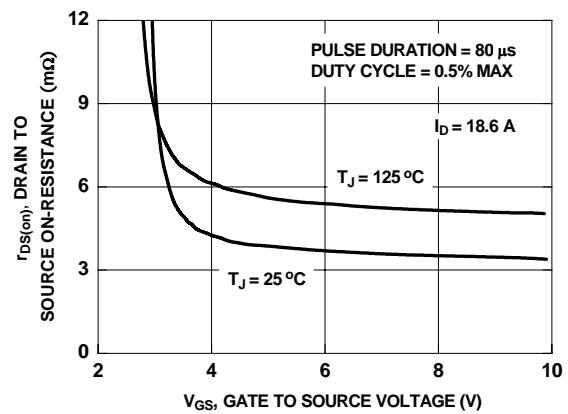


Figure 4. On-Resistance vs Gate to Source Voltage

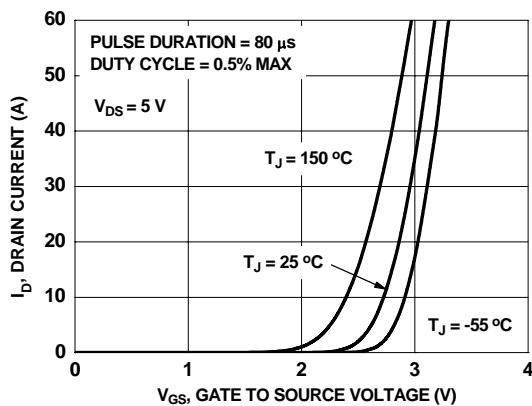


Figure 5. Transfer Characteristics

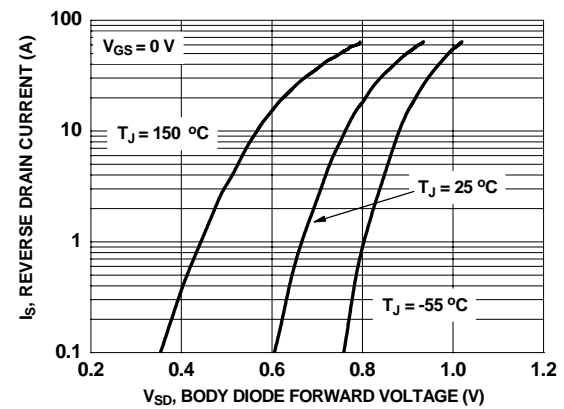


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

# Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

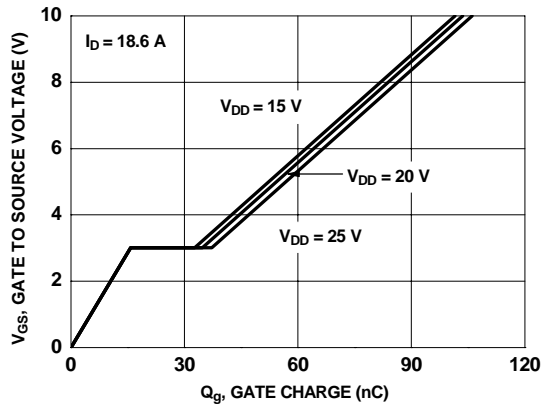


Figure 7. Gate Charge Characteristics

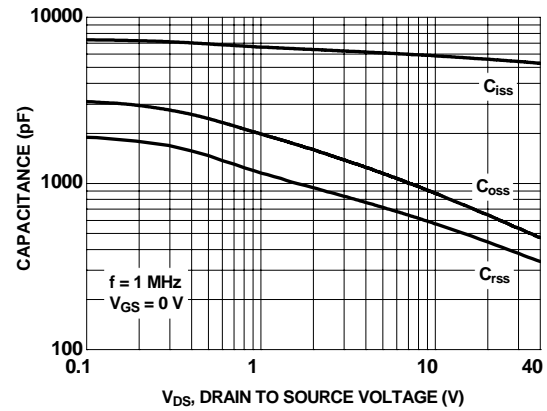


Figure 8. Capacitance vs Drain to Source Voltage

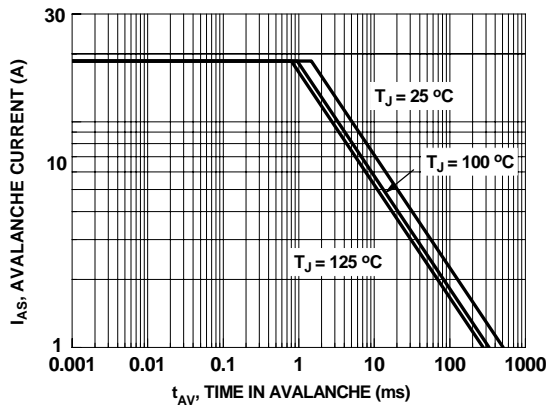


Figure 9. Unclamped Inductive Switching Capability

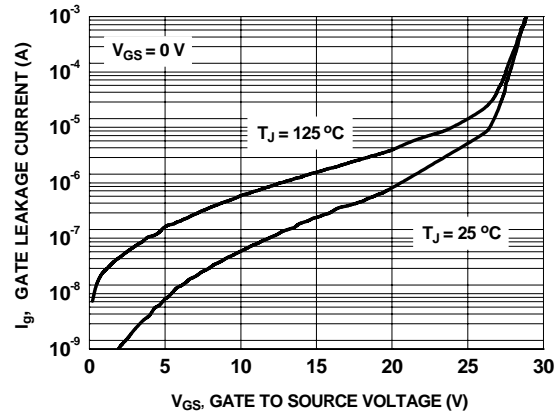


Figure 10.  $I_{gss}$  vs  $V_{GS}$

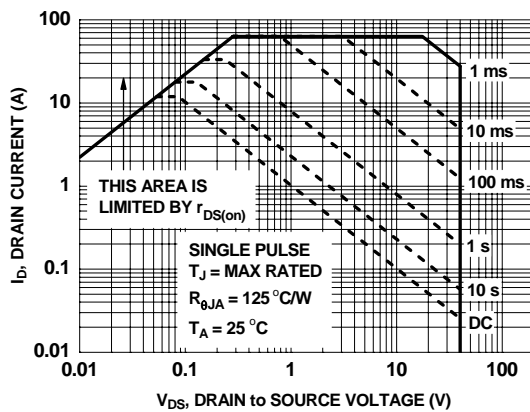


Figure 11. Forward Bias Safe Operating Area

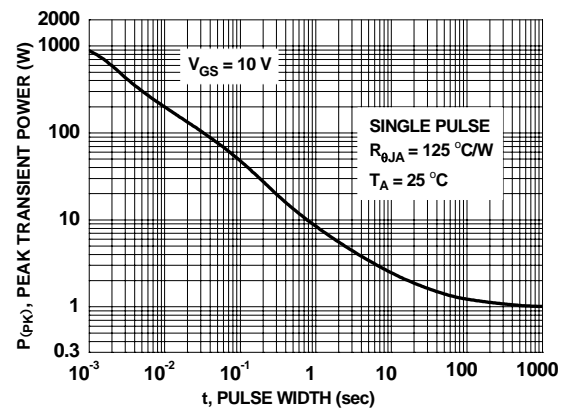
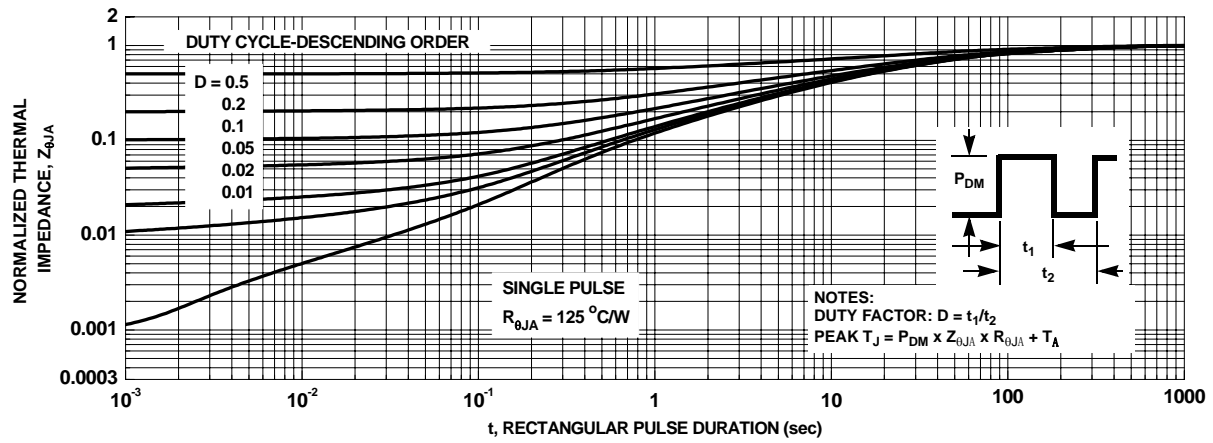


Figure 12. Single Pulse Maximum Power Dissipation



# Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted







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